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QUADRUPLE 2-INPUT NAND GATES

Description

The 74HC00 provides provides four independent 2-input NAND gates with standard push-pull outputs. The device is designed for operation with a power supply range of 2.0V to 6.0V.

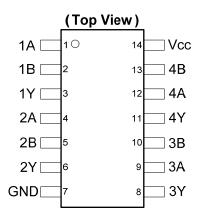
The gates perform the Boolean function:

$$Y = \overline{A \bullet B}$$
 or $Y = \overline{A} + \overline{B}$

Features

- Wide Supply Voltage Range from 2.0V to 6.0V
- Sinks or Sources 4mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- · Schmitt Trigger Action at All Inputs
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



SO-14 / TSSOP-14

Applications

- General Purpose Logic
- · Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

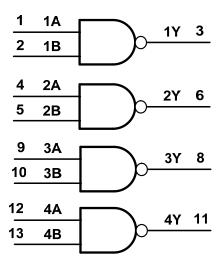
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	V _{CC}	Supply Voltage

Logic Diagram



Function Table

Inp	Output	
Α	В	Υ
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V_{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range (Note 5)	-0.5 to +7.0	V
I _{IK}	Input Clamp Current $V_1 < -0.5V$ or $V_1 > V_{CC} + 0.5V$	±20	mA
I _{OK}	Output Clamp Current V _O < -0.5V or V _O > V _{CC} +0.5V	±20	mA
Ιο	Continuous output current -0.5V < V _O V _{CC} +0.5V	+/- 25	mA
Icc	Continuous current through Vcc	50	mA
I _{GND}	Continuous current through GND	-50	mA
TJ	T _J Operating Junction Temperature		°C
T _{STG}	T _{STG} Storage Temperature		°C
Ртот	Total Power Dissipation	500	mW

Notes:

Recommended Operating Conditions (Note 6) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
Vcc	Supply Voltage		2.0	6.0	V
VI	Input Voltage		0	V_{CC}	V
Vo	Output Voltage		0	V _{CC}	V
		V _{CC} = 2.0V		625	
Δt/ΔV	Input transition rise or fall rate	V _{CC} = 4.5V		140	ns/V
		V _{CC} = 6.0V		85	
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 6. Unused inputs should be held at V_{CC} or Ground.

Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values. V_{CC} to the extent the maximum clamp current is exceeded.

^{5.} Input Voltage cannot exceed Vcc to the extent the Maximum clamp current is exceeded.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Comple ed	Downwater	Took Conditions		$T_A = -40^\circ$	°C to 85°C	T _A = -40°	C to 125°C	l lmi4
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
			2.0V	1.5		1.5		
V_{IH}	High-level Input Voltage		4.5V	3.15		3.15		V
	Voltage		6.0V	4.2		4.2		
	Laurelian d		2.0V		0.5		0.5	
V_{IL}	Low-level input voltage		4.5V		1.35		1.35	V
	voltage		6.0V		1.8		1.8	
		$I_{OH} = -20 \mu A$	2.0V	1.9		1.9		V
		I _{OH} = -20μA	4.5V	4.4		4.4		
V_{OH}	High-level Output Voltage	I _{OH} = -20μA	6.0V	5.9		5.9		
	Voltage	I _{OH} = -4.0mA	4.5V	3.84		3.7		
		I _{OH} = -5.2mA	6.0V	5.34		5.2		
		I _{OL} = 20μA	2.0V		0.1		0.1	
		I _{OL} = 20μA	4.5V		0.1		0.1	
V_{OL}	Low-level Output Voltage	I _{OL} = 20μA	6.0V		0.1		0.1	V
	Voltage	I _{OL} = 4mA	4.5V		0.33		0.44	
		I _{OL} = 5.2mA	6.0V		0.33		0.44	
lį	Input Current	V _I =GND to 5.5V	6.0V		± 1		± 1	μΑ
Icc	Supply Current	$V_I = GND \text{ or } V_{CC}, I_O = 0$	6.0V	_	20		40	μΑ

Switching Characteristics

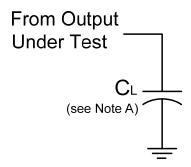
Symbol	Parameter	Test	Vcc	•	Γ _A = +25°0		-40°C to +85°C	-40°C to +125°C	Unit	
Symbol	raiailletei	Conditions	V CC	Min	Тур.	Max	Max	Max	Oilit	
	Dropogation	Figure 1	2.0V		25	90	115	135		
t _{PD}	Propagation Delay A _N to Y _N	Figure 1 $C_1 = 50pF$	4.5V		9	18	23	27	ns	
	Delay AN to TN	Delay An to Th	C _L = 50pF	6.0V		7	15	20	23	
		Figure 1	2.0V		19	75	95	110		
t _t	Transition Time	Figure 1 $C_L = 50pF$	4.5V		7	15	19	22	ns	
		CL = 30pi	6.0V	_	6	13	16	19		

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

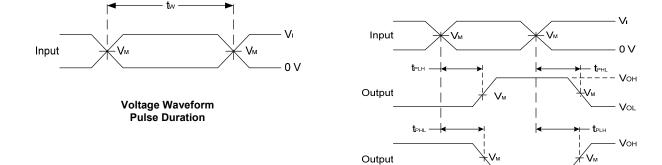
Parameter		Test Conditions	V _{CC} = 6V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	22	pF
Cı	Input Capacitance	$V_1 = V_{CC} - \text{or GND}$	4	pF



Parameter Measurement Information



Vcc	Inp	Inputs V _M		CL
	VI	t _r /t _f		
2.0V to 6.0V	V _{CC}	6ns	V _{CC} /2	15pF,50pF



Voltage Waveform **Propagation Delay Times** Inverting and Non Inverting Outputs

- Notes: A . Includes test lead and test apparatus capacitance.

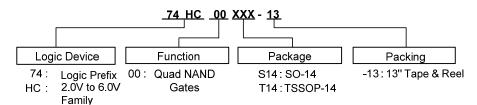
 - B. All pulses are supplied at pulse repetition rate ≤ 1 MHz
 C. Inputs are measured separately one transition per measurement
 - D. t_{PLH} and t_{PHL} are the same as t_{PD}

Figure 1 Load Circuit and Voltage Waveforms

- Vol



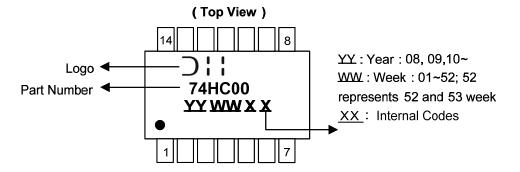
Ordering Information



	Device Package Code		Packaging	7" Tape and Reel		
		Fackage Code	rackaging	Quantity	Part Number Suffix	
Pby Lead-free Green	74HC00S14-13	S14	SO-14	2500/Tape & Reel	-13	
Pb. Lead-free Green	74HC00T14-13	T14	TSSOP-14	2500/Tape & Reel	-13	

Marking Information

(1) SO-14, TSSOP-14



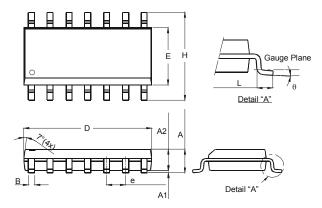
Part Number	Package
74HC00S14	SO-14
74HC00T14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

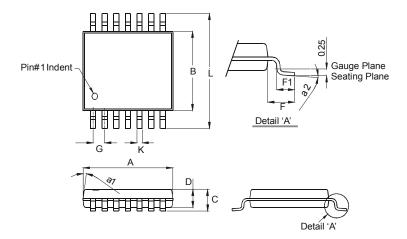
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



	SO-14					
Dim	Min	Max				
Α	1.47	1.73				
A1	0.10	0.25				
A2	1.45	Тур				
В	0.33	0.51				
D	8.53	8.74				
Е	3.80	3.99				
е	1.27	Тур				
Н	5.80	6.20				
L	0.38	1.27				
θ	0°	8°				
All Di	mensions	s in mm				

Package Type: TSSOP-14

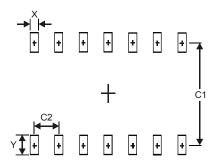


	TSSOP-14					
Dim	im Min Max					
a1	7° (4X)				
a2	0°	8°				
Α	4.9	5.10				
В	4.30	4.50				
С	_	1.2				
D	0.8	1.05				
F	1.00	Тур				
F1	0.45	0.75				
G	0.65	Тур				
K	0.19	0.30				
L	6.40	Тур				
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for latest version.

Package Type: SO-14

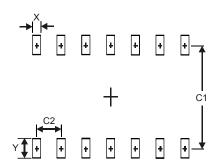


Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27



Suggested Pad Layout (cont.)

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Υ	1.45
C1	5.9
C2	0.65

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